

AMENDMENT TRANSMITTAL LETTER (Large Entity)

Applicant(s): Stephen W. Bedell, et al.

Docket No.

YOR920030102US2 (16476Z)

Application No. 10/696,601	Filing Date 10/29/2003	Examiner S. J. Stein	Customer No. 23389	Group Art Unit 1775	Confirmation No. 6851
-------------------------------	---------------------------	-------------------------	-----------------------	------------------------	--------------------------

Invention: **FORMATION OF SILICON-GERMANIUM-ON-INSULATOR (SGOI) BY AN INTEGRAL HIGH TEMPERATURE SIMOX-Ge INTERDIFFUSION ANNEAL**

AUG 09 2004

COMMISSIONER FOR PATENTS:

Transmitted herewith is an amendment in the above-identified application.

The fee has been calculated and is transmitted as shown below.

CLAIMS AS AMENDED

	CLAIMS REMAINING AFTER AMENDMENT	HIGHEST # PREV. PAID FOR	NUMBER EXTRA CLAIMS PRESENT	RATE	ADDITIONAL FEE
TOTAL CLAIMS	46 -	38 =	8	x \$18.00	\$144.00
INDEP. CLAIMS	1 -	3 =	0	x \$86.00	\$0.00
Multiple Dependent Claims (check if applicable)					\$0.00
					\$144.00
					TOTAL ADDITIONAL FEE FOR THIS AMENDMENT

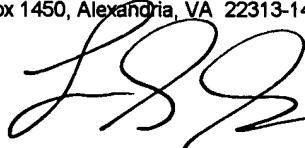
- No additional fee is required for amendment.
- Please charge Deposit Account No. 50-0510/IBM in the amount of \$144.00
- A check in the amount of _____ to cover the filing fee is enclosed.
- The Director is hereby authorized to charge payment of the following fees associated with this communication or credit any overpayment to Deposit Account 50-0510/IBM
 - Any additional filing fees required under 37 C.F.R. 1.16.
 - Any patent application processing fees under 37 CFR 1.17.



Dated: August 6, 2004

Leslie S. Szivos, Ph.D.
Registration No. 39,394

I certify that this document and fee is being deposited on 8/6/2004 with the U.S. Postal Service as first class mail under 37 C.F.R. 1.8 and is addressed to the Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.



Signature of Person Mailing Correspondence

Leslie S. Szivos, Ph.D.

Typed or Printed Name of Person Mailing Correspondence

cc:



JRW

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s):

Stephen W. Bedell, et al.

Examiner: S.J. Stein

Serial No.:

10/696,601

Art Unit: 1775

Filed:

October 29, 2003

Docket: YOR920030102US2 (16476Z)

For: FORMATION OF SILICON-GERMANIUM-
ON-INSULATOR (SGOI) BY AN INTEGRAL
HIGH TEMPERATURE SIMOX-Ge INTERDIFFUSION ANNEAL

Dated: August 6, 2004

Confirmation No.: 6851

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

RESPONSE UNDER 37 C.F.R. § 1.111

Sir:

In response to the Office Action dated May 6, 2004, applicants submit the following amendments and remarks for entry of record in the above-identified patent application. In addition to this submission, applicants have also enclosed a Terminal Disclaimer signed by Robert M. Trepp. Mr. Trepp is an attorney of record who is listed on the original signed Declaration.

CERTIFICATE OF MAILING UNDER 37 C.F.R. §1.8(a)

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, Box 1450, Alexandria, VA 22313-1450 on August 6, 2004.

Dated: August 6, 2004

A handwritten signature in black ink, appearing to read "Leslie S. Szivos, Ph.D."